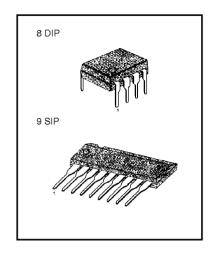
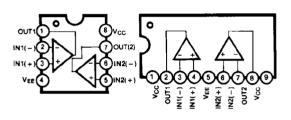
## **DUAL JFET INPUT OPERATIONAL**

### **FEATURES**

- Low supply current: 400pA MAX
- Low input bias Current: 50pA MAX
  Low input offset voltage: 1mV MAX
- High slew rate: 1V/μs
- High gain bandwidth: 1MHz



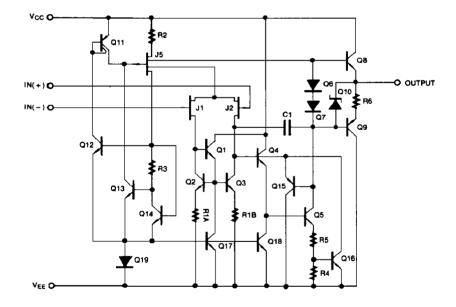
# **BLOCK DIAGRAM**



### **ORDERING INFORMATION**

Device	Package	Operating Temperature				
LM442N LM442 <b>A</b> N	8 DIP					
LM442S LM442AS	9 SIP	0 ~ +70°C				

# SCHEMATIC DIAGRAM (One Section Only)





# **ABSOLUTE MAXIMUM RATINGS**

Characteristics	Symbol	Value	Unit
Power Supply Voltage LM442	Vcc	±18	v
LM442A	V cc	±20	<b>'</b>
Differential Input Voltage	$V_{I(DIFF)}$	30	٧
Input Voltage range	V <sub>I</sub>	±15	V
Output Short Circuit Duration		Continuous	
Power Dissipation	P <sub>D</sub>	670	mW
Operating Temperature Range LM442/A	T <sub>OPR</sub>	0 ~ + 70	°C
Storage Temperature Range	Т <sub>sта</sub>	-65 ~ + 150	°C

### **ELECTRICAL CHARACTERISTICS**

(T<sub>A</sub>=25 °C, unless otherwise specified)

		Test Conditions		LM442A			LM442			[ ]
Characteristic	Svmbol			Min	Тур	Max	Min	Тур	Max	Init
Input Offset Voltage	V <sub>IO</sub>	R <sub>S</sub> =10KΩ			0.5	1.0		1.0	5.0	mV
	-		Note 1						7.5	
Input Offset Voltage Drift	ΔV <sub>10</sub> /ΔΤ	$R_S = 10K\Omega$			7	10		7		μV/°C
Input Offset Current	l <sub>io</sub>		N . 4		5	25		5	50	p <b>A</b>
	+	-	Note 1		10	15		10	15	
Large Signal Voltage Gain	IBIAS		Note 1		10	50 30		10	100 30	рA
		$R_L = 10K\Omega$	Note i	50	200	30	25	200	30	
Large Signal Voltage Gain	Gv	$V_{O(P,P)} = \pm 0V$	Note 1	25	200		15	200		V/mV
Output Voltage Swing	V <sub>O(P-P)</sub>	$R_S = 10K\Omega$	Note	±17	±18		±12	±13		V
Input Voltage Range	V <sub>I(R)</sub>			±16	+18 -17		±11	+15 -12		٧
Common-Mode Rejection Ratio	CMRR	R <sub>s</sub> ≤10KΩ		80	100		70	95		dB
Power Supply Rejection Ratio	PSRR	R <sub>s</sub> ≤10KΩ		80	100		70	90		dB
Input Resistance	Rı				10 <sup>12</sup>		10 <sup>12</sup>			Ω
Supply Current	lcc				300	400		400	500	μА
Slew Rate	SR			8.0	1		0.6	1		V/µS
Gain Bandwidth Product				8.0	1		0.6	1		MHz
Channel Separation	cs	f = 1Hz-20KHz (input reference			120			120		dB
Equivalent Input Noise Voltage	V <sub>NI</sub>	$R_S = 100\Omega$ f = 1 KHz			35			35		n <u>V/</u> √Hz
Equivalent Input Noise Current	I <sub>NI</sub>	f = 1KHz			0.01			0.01		p <b>A</b> / √ Hz

NOTE 1. LM442/A :  $0 \le T_A \le +70$  °C



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FACT<sup>TM</sup> QS<sup>TM</sup>

FACT Quiet Series  $^{\text{TM}}$  Quiet Series  $^{\text{TM}}$  SuperSOT  $^{\text{TM}}$ -3 FAST  $^{\text{TM}}$  SuperSOT  $^{\text{TM}}$ -6 GTO  $^{\text{TM}}$  SuperSOT  $^{\text{TM}}$ -8 HiSeC  $^{\text{TM}}$ 

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#### **PRODUCT STATUS DEFINITIONS**

#### **Definition of Terms**

Datasheet Identification	Product Status	Definition
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